

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

*Note:*

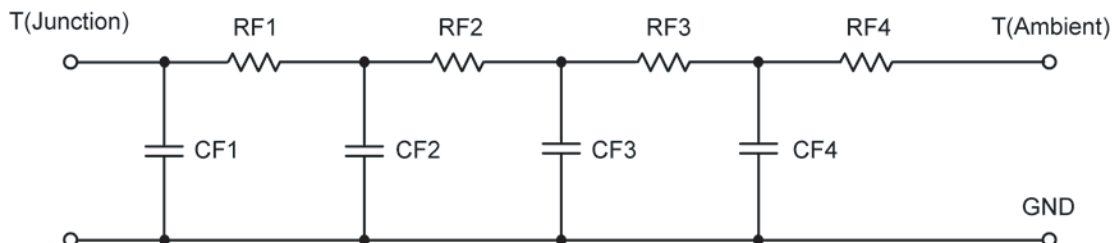
*For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).*

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
<b>Thermal Resistance (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RT1	22.2455	N/A	7.0334
RT2	6.5433	N/A	900.0248 m
RT3	13.6916	N/A	6.0314
RT4	39.0314	N/A	8.9996
<b>Thermal Capacitance (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CT1	40.7641 m	N/A	38.9102 m
CT2	8.0789 m	N/A	1.0458 m
CT3	339.0512 m	N/A	12.1480 m
CT4	1.9953	N/A	234.8954 m

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	5.1752	N/A	1.8942
RF2	24.0627	N/A	10.6579
RF3	15.3329	N/A	5.9029
RF4	36.8248	N/A	4.5351
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	4.0704 m	N/A	1.8866 m
CF2	21.3609 m	N/A	8.7107 m
CF3	152.9699 m	N/A	79.0138 m
CF4	1.8083	N/A	412.1253 m

Note: NA indicates not applicable

## Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

